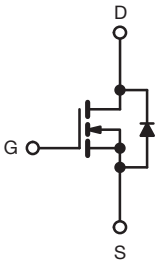
E Series Power MOSFET

Thin-Lead TO-220 FULLPAK





N-Channel MOSFET

FEATURES

- Low figure-of-merit (FOM) R_{on} x Q_g
- Low input capacitance (C_{iss})
- Reduced switching and conduction losses
- Ultra low gate charge (Q_g)
- Avalanche energy rated (UIS)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE Available

APPLICATIONS

- Server and telecom power supplies
- Switch mode power supplies (SMPS)
- Power factor correction power supplies (PFC)
- Lighting
  - High-intensity discharge (HID)
  - Fluorescent ballast lighting
- Industrial
  - Welding
  - Induction heating
  - Motor drives
  - Battery chargers
  - Renewable energy
  - Solar (PV inverters)

PRODUCT SUMMARY		
V_{DS} (V) at T_J max.	700	
$R_{DS(on)}$ max. (Ω) at 25 °C	V_{GS} = 10 V	0.6
Q_g max. (nC)	48	
Q_{gs} (nC)	6	
Q_{gd} (nC)	11	
Configuration	Single	

ORDERING INFORMATION	
Package	Thin-Lead TO-220 FULLPAK
Lead (Pb)-free	SiHA6N65E-E3
Lead (Pb)-free and halogen-free	SiHA6N65E-GE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER			SYMBOL	LIMIT	UNIT
Drain-source voltage			V_{DS}	650	V
Gate-source voltage			V_{GS}	± 30	
Continuous drain current (T_J = 150 °C) [e]	V_{GS} at 10 V	T_C = 25 °C	I_D	7	A
		T_C = 100 °C		5	
Pulsed drain current [a]			I_{DM}	18	
Linear derating factor				0.63	W/°C
Single pulse avalanche energy [b]			E_{AS}	56	mJ
Maximum power dissipation			P_D	31	W
Operating junction and storage temperature range			T_J, T_{stg}	-55 to +150	°C
Drain-source voltage slope	T_J = 125 °C		dV/dt	37	V/ns
Reverse diode dV/dt [d]				27	
Soldering recommendations (peak temperature) [c]	For 10 s			300	°C
Mounting torque	M3 screw			0.6	Nm

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature
b. V_{DD} = 50 V, starting T_J = 25 °C, L = 28.2 mH, R_g = 25 Ω, I_{AS} = 2 A
c. 1.6 mm from case
d. $I_{SD} \leq I_D$, dI/dt = 100 A/µs, starting T_J = 25 °C
e. Limited by maximum junction temperature

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THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	TYP.	MAX.	UNIT
Maximum junction-to-ambient	R_{thJA}	43	65	°C/W
Maximum junction-to-case (drain)	R_{thJC}	3.1	4.0	

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	650	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	Reference to 25 °C, I_D = 1 mA	-	0.73	-	V/°C
Gate-source threshold voltage (N)	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	2	-	4	V
Gate-source leakage	I_{GSS}	V_{GS} = ± 20 V	-	-	± 100	nA
		V_{GS} = ± 30 V	-	-	± 1	µA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 650 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 520 V, V_{GS} = 0 V, T_J = 125 °C	-	-	10	
Drain-source on-state resistance	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 3 A	-	0.5	0.6	Ω
Forward transconductance	g_{fs}	V_{DS} = 30 V, I_D = 3 A	-	2	-	S
Dynamic						
Input capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 100 V, f = 1 MHz	410	820	1640	pF
Output capacitance	C_{oss}		20	40	80	
Reverse transfer capacitance	C_{rss}		2	4	8	
Effective output capacitance, energy related [a]	$C_{o(er)}$	V_{DS} = 0 V to 520 V, V_{GS} = 0 V	-	36	-	
Effective output capacitance, time related [b]	$C_{o(tr)}$		-	117	-	
Total gate charge	Q_g	V_{GS} = 10 V; I_D = 3 A, V_{DS} = 520 V	-	24	48	nC
Gate-source charge	Q_{gs}		-	6	-	
Gate-drain charge	Q_{gd}		-	11	-	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 520 V, I_D = 3 A, V_{GS} = 10 V, R_g = 9.1 Ω	-	14	28	ns
Rise time	t_r		-	12	24	
Turn-off delay time	$t_{d(off)}$		-	30	60	
Fall time	t_f		-	20	40	
Gate input resistance	R_g	f = 1 MHz, open drain	0.4	1.4	2.7	Ω
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	MOSFET symbol showing the integral reverse p - n junction diode 	-	-	7	A
Pulsed diode forward current	I_{SM}		-	-	18	
Diode forward voltage	V_{SD}	T_J = 25 °C, I_S = 3 A, V_{GS} = 0 V	-	0.83	1.3	V
Reverse recovery time	t_{rr}	T_J = 25 °C, I_F = I_S = 3 A, dI/dt = 100 A/µs, V_R = 25 V	118	237	474	ns
Reverse recovery charge	Q_{rr}		-	2.2	-	µC
Reverse recovery current	I_{RRM}		-	16	-	A

Notes

a. $C_{oss(er)}$ is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS}

b. $C_{oss(tr)}$ is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS}

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

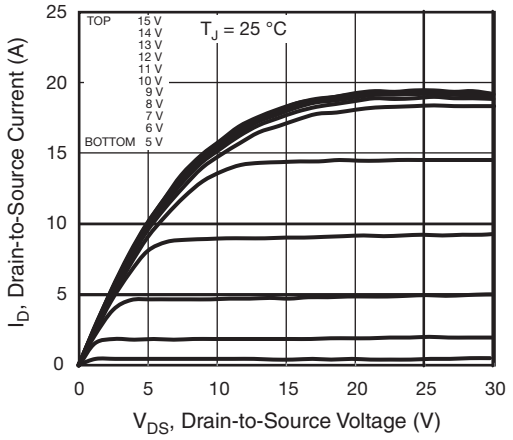


Fig. 1 - Typical Output Characteristics

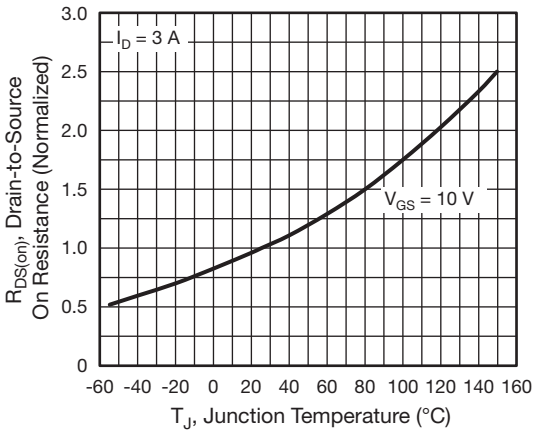


Fig. 4 - Normalized On-Resistance vs. Temperature

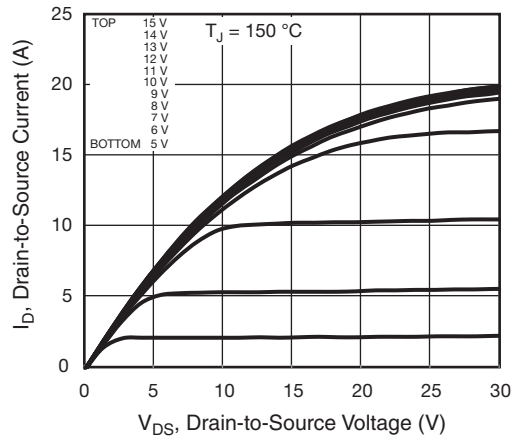


Fig. 2 - Typical Output Characteristics

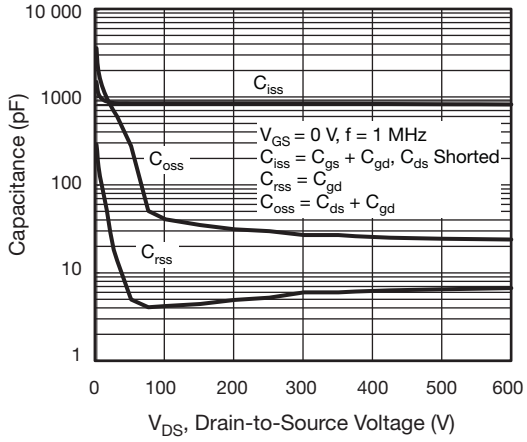


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

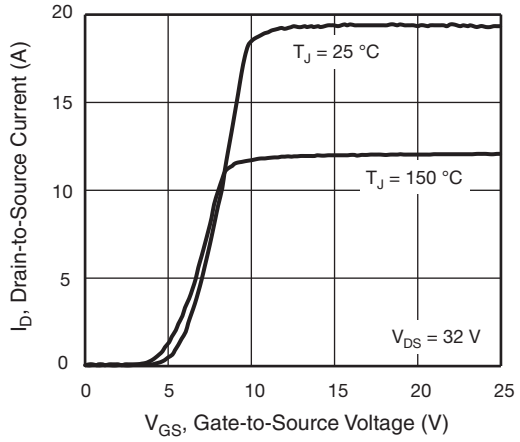


Fig. 3 - Typical Transfer Characteristics

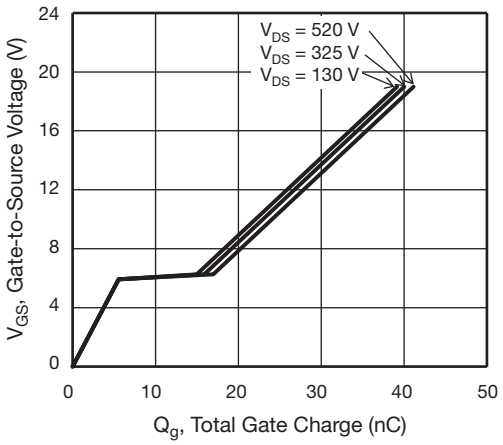


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

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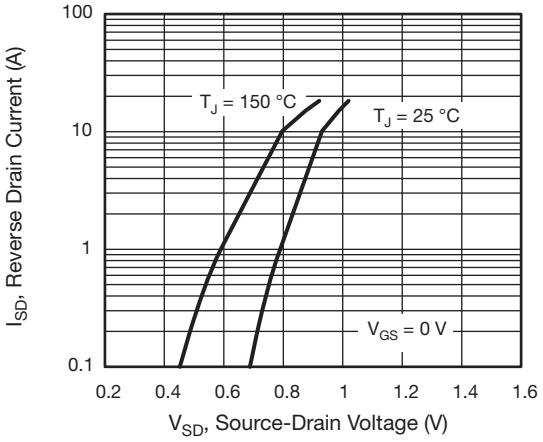


Fig. 7 - Typical Source-Drain Diode Forward Voltage

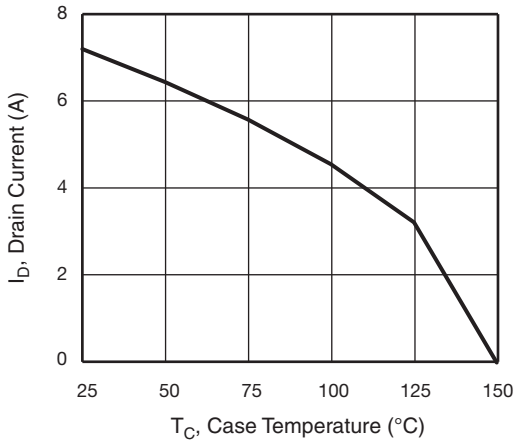


Fig. 9 - Maximum Drain Current vs. Case Temperature

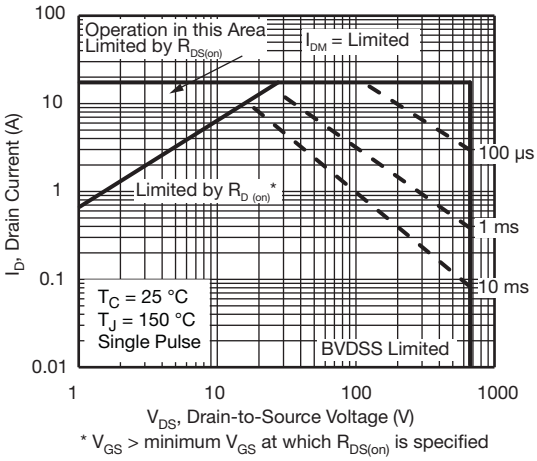


Fig. 8 - Maximum Safe Operating Area

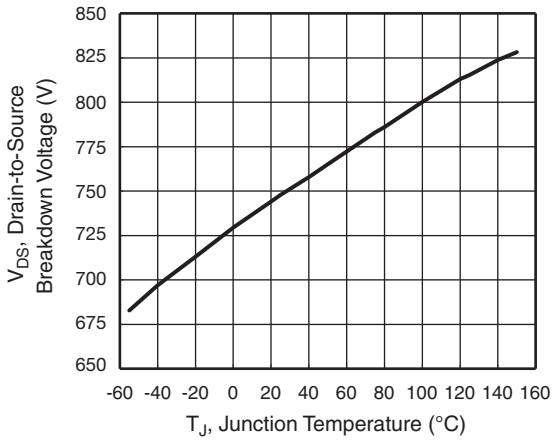


Fig. 10 - Temperature vs. Drain-to-Source Voltage

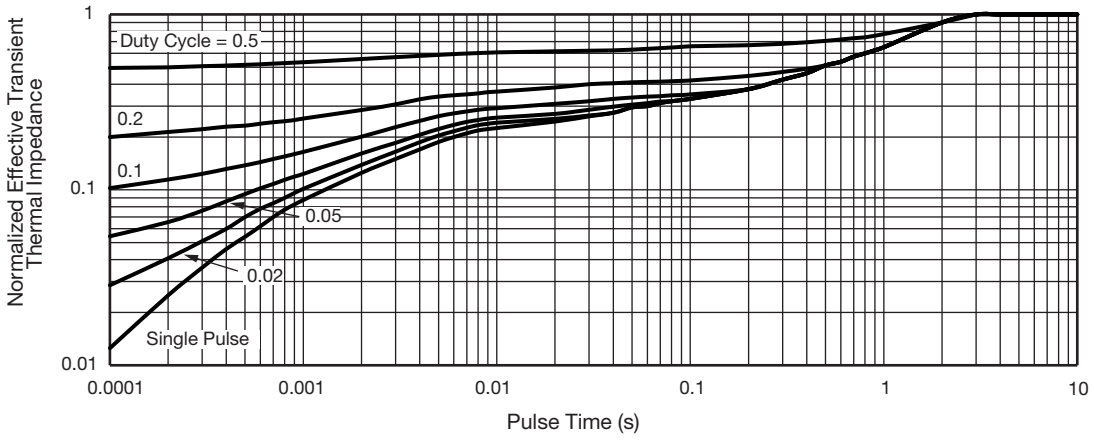


Fig. 11 - Normalized Thermal Transient Impedance, Junction-to-Case

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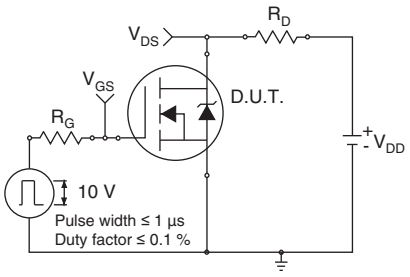


Fig. 12 - Switching Time Test Circuit

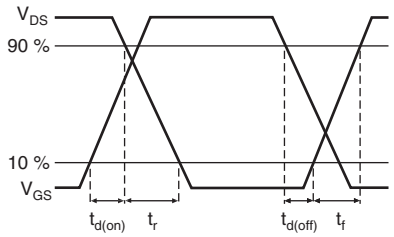


Fig. 13 - Switching Time Waveforms

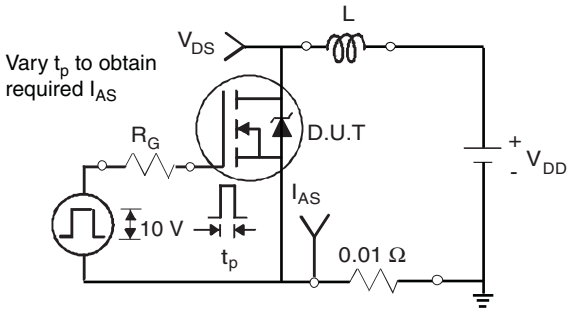


Fig. 14 - Unclamped Inductive Test Circuit

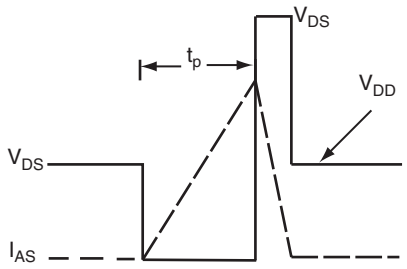


Fig. 15 - Unclamped Inductive Waveforms

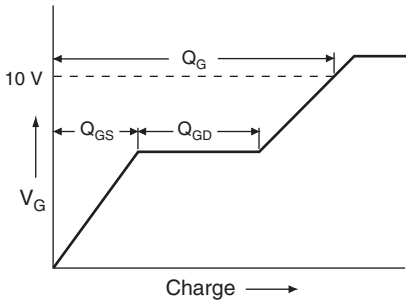


Fig. 16 - Basic Gate Charge Waveform

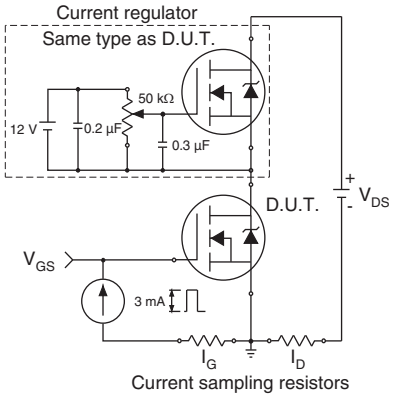
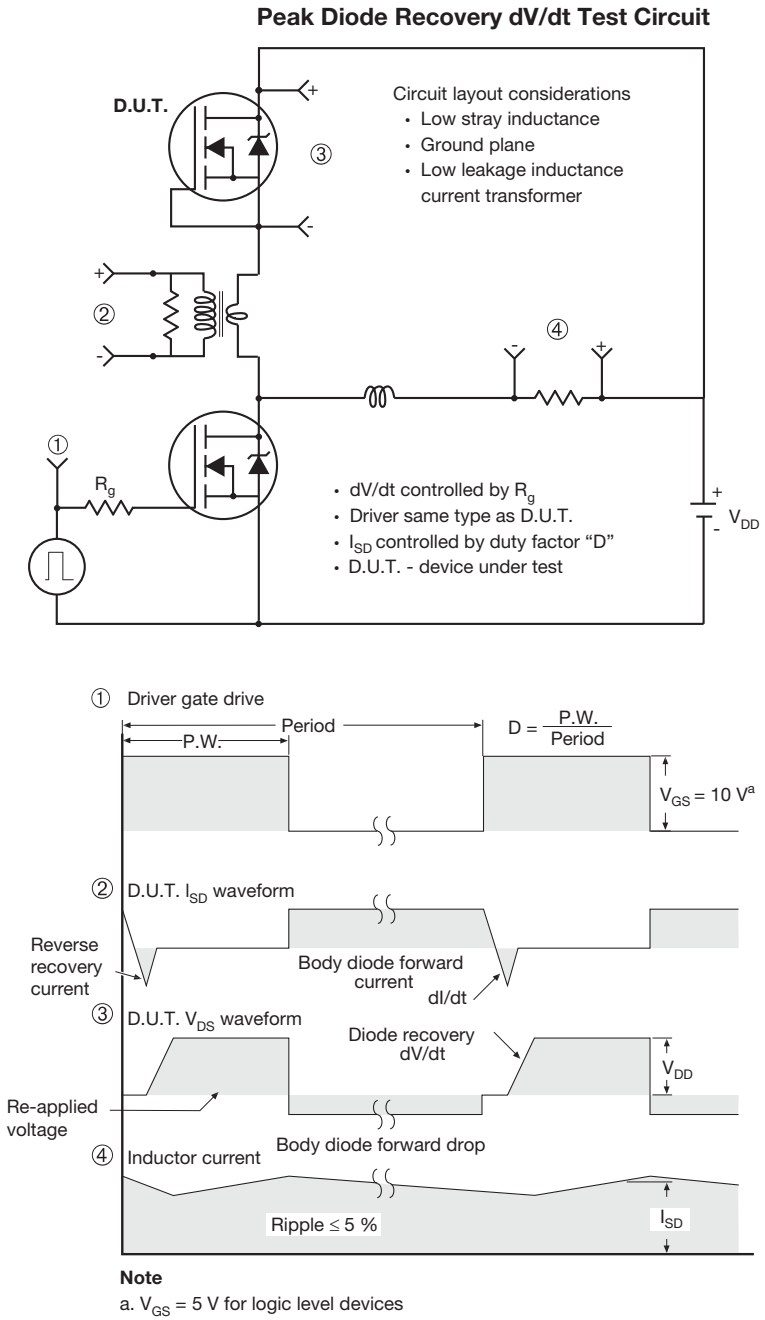


Fig. 17 - Gate Charge Test Circuit

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Note

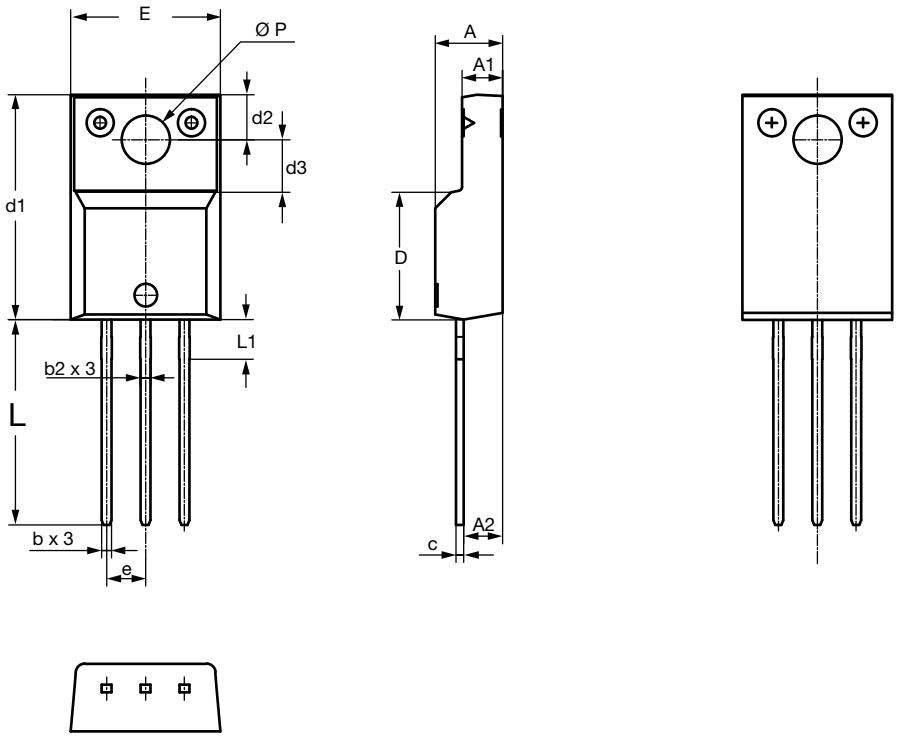
a. V_{GS} = 5 V for logic level devices

Fig. 18 - For N-Channel

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TO-220 FULLPAK Thin Lead



SYMBOL	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.30	4.70	0.169	0.185
A1	2.50	2.90	0.098	0.114
A2	2.40	2.80	0.094	0.110
b	0.60	0.80	0.024	0.031
b2	0.60	0.90	0.024	0.035
c	-	0.60	-	0.024
D	8.30	8.70	0.327	0.342
d1	14.70	15.30	0.579	0.602
d2	2.90	3.10	0.114	0.122
d3	3.30	3.70	0.130	0.146
E	9.70	10.30	0.382	0.406
e	2.50	2.70	0.098	0.106
L	13.40	13.80	0.528	0.543
L1	1.00	2.80	0.039	0.110
Ø P	3.00	3.40	0.118	0.134

ECN: E20-0684-Rev. D, 28-Dec-2020
DWG: 6021

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